Product data sheet

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NXP Semiconductors



General purpose PIN diode

BAP51-02

FEATURES

- Low diode capacitance
- Low diode forward resistance.

APPLICATIONS

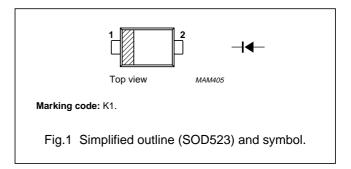
· General RF applications.

DESCRIPTION

General purpose PIN diode in a SOD523 ultra small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	60	V
I _F	continuous forward current		_	50	mA
P _{tot}	total power dissipation	T _s = 90 °C	_	715	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA	_	0.95	1.1	V
V _R	reverse voltage	I _R = 10 μA	50	_	_	V
I _R	reverse current	V _R = 50 V	-	_	100	nA
C _d	diode capacitance	V _R = 0; f = 1 MHz	Ī-	0.4	_	pF
		V _R = 1 V; f = 1 MHz	_	0.3	0.55	pF
		V _R = 5 V; f = 1 MHz	-	0.2	0.35	pF
r _D	diode forward resistance	I _F = 0.5 mA; f = 100 MHz; note 1	_	5.5	9	Ω
		I _F = 1 mA; f = 100 MHz; note 1	_	3.6	6.5	Ω
		I _F = 10 mA; f = 100 MHz; note 1	_	1.5	2.5	Ω

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	85	K/W

General purpose PIN diode

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GRAPHICAL DATA

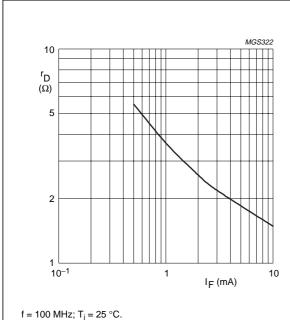


Fig.2 Forward resistance as a function of forward current; typical values.

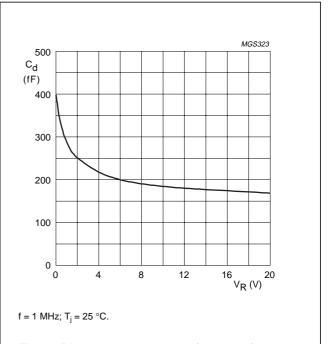
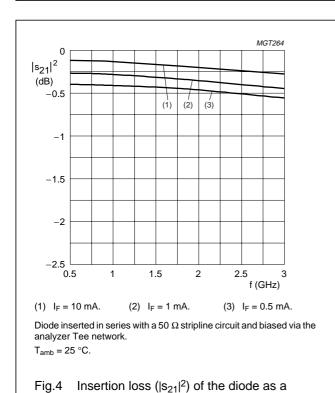


Fig.3 Diode capacitance as a function of reverse voltage; typical values.



function of frequency; typical values.

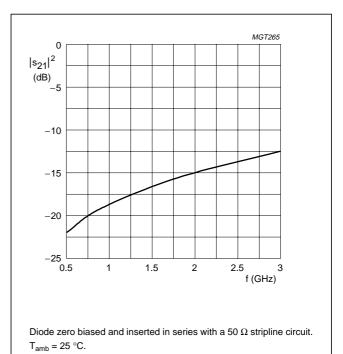


Fig.5 Isolation ($|s_{21}|^2$) of the diode as a function of frequency; typical values.

NXP Semiconductors Product specification

General purpose PIN diode

BAP51-02

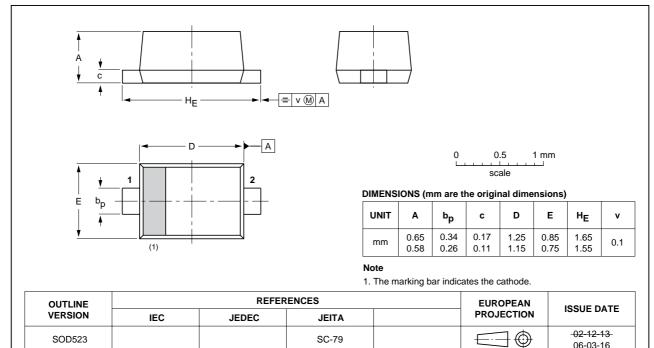
06-03-16

PACKAGE OUTLINE

SOD523



SOD523



SC-79

NXP Semiconductors BAP51-02

General purpose PIN diode

Legal information

Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NXP Semiconductors BAP51-02

General purpose PIN diode

Revision history

Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP51-02_N_3	20080102	Product data sheet	-	BAP51-02_2
Modifications:	 Package out 	tline drawing on page 4 change	ed	
BAP51-02_2 (9397 750 07151)	20000706	Product specification	-	BAP51-02_N_1
BAP51-02_N_1 (9397 750 06152)	19990628	Preliminary specification	-	-

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BAP51-02,115 BAP51-02,315



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Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина,

дом 2, корпус 4, литера А.